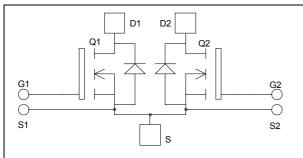


Dual Common Source MOSFET Power Module

 $V_{DSS} = 100V$ $I_D = 495A$ @ Tc = 25°C



Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V	
T	Continuous Drain Current	$T_c = 25$ °C	495		
I_D	Continuous Diam Current	$T_c = 80$ °C	370	A	
I_{DM}	Pulsed Drain current		1900		
V_{GS}	Gate - Source Voltage		±30	V	
R _{DSon}	Drain - Source ON Resistance		2.5	$m\Omega$	
P_D	Maximum Power Dissipation $T_c = 25^{\circ}C$		1250	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A	
E_{AR}	Repetitive Avalanche Energy		50	mJ	
E_{AS}	Single Pulse Avalanche Energy		3000	1113	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25$ °C			400	^	
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			2000	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 200A$			2.25	2.5	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10$ mA		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±400	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		40		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		15.7		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		5.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		1360		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 50V$		240		nC
Q_{gd}	Gate – Drain Charge	$I_D = 400A$		720		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		160		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		240		nc
$T_{d(off)}$	Turn-off Delay Time	$I_{D} = 400A$		500		ns
T_{f}	Fall Time	$R_G = 1.25\Omega$		160		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		2.2		ma I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.41		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2.43		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.56		mJ

Source - Drain diode ratings and characteristics

Source	Dram aloae ratings and t	mu acter istics					
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			495	Α
	(Body diode)		$Tc = 80^{\circ}C$			370	Λ
$ m V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -400$	$V_{GS} = 0V, I_S = -400A$			1.3	V
dv/dt	Peak Diode Recovery •					5	V/ns
t_{rr}	Reverse Recovery Time	$I_{S} = -400A$ $V_{R} = 66V$	$T_j = 25^{\circ}C$		270		ns
Qrr	Reverse Recovery Charge	$di_S/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		11.6		μC

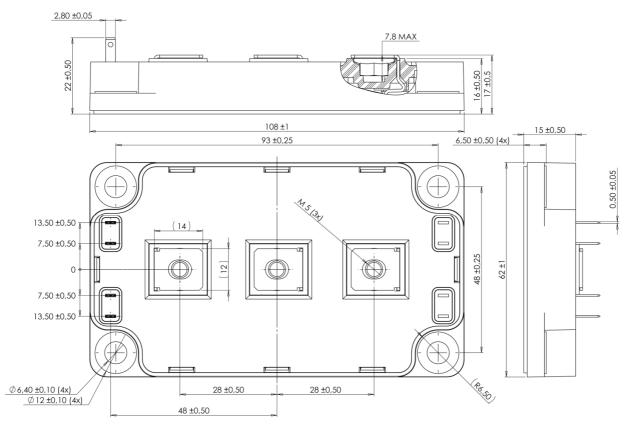
• dv/dt numbers reflect the limitations of the circuit rather than the device itself.



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.1	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150	°C	
T_{STG}	Storage Temperature Range Operating Case Temperature			-40			125
$T_{\rm C}$				-40			100
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

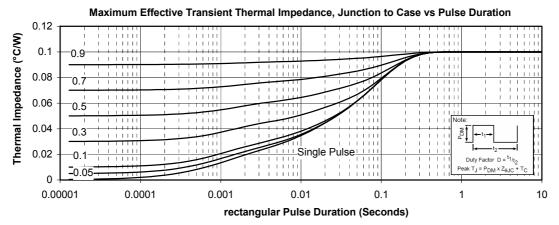
SP6 Package outline (dimensions in mm)

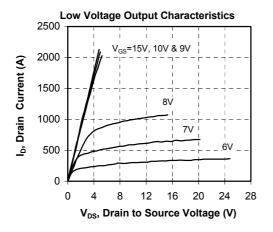


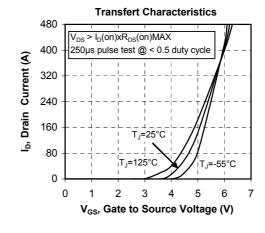
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

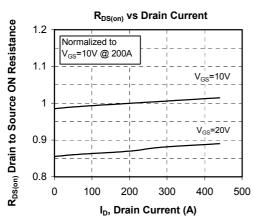


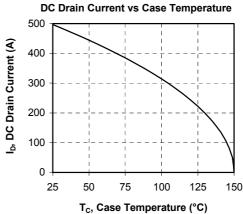
Typical Performance Curve





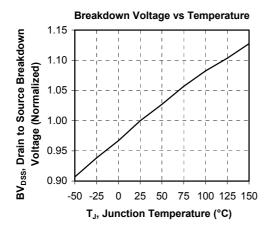


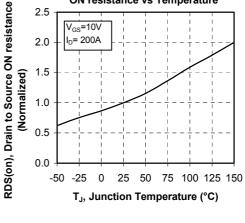


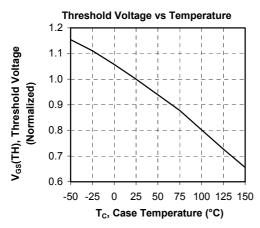


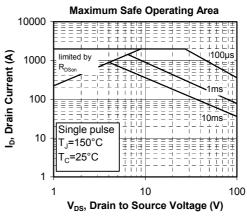


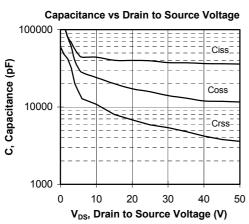
ON resistance vs Temperature

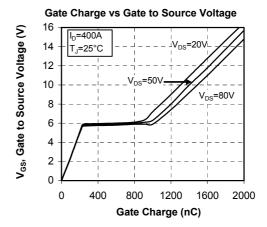




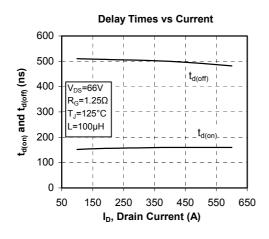


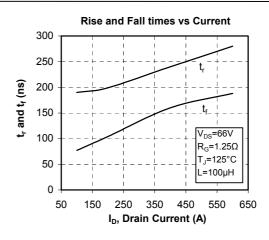


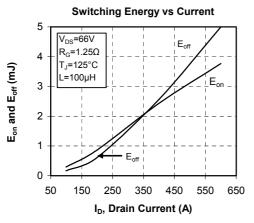


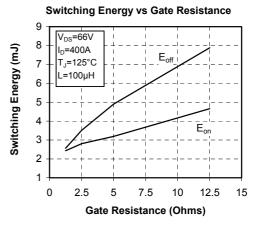


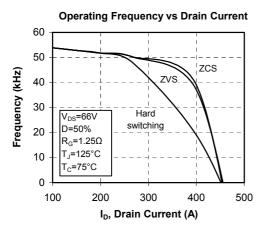


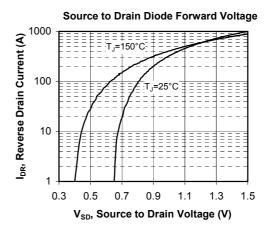














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